

### HIGH FREQUENCY LOW NOISE AMPLIFIER

### NPN SILICON EPITAXIAL TRANSISTOR

#### DESCRIPTION

The 2SC2570A is designed for use in Low Noise Amplifier of VHF & UHF stages.

#### FEATURES

- Low noise and high gain : NF = 1.5 dB TYP., Ga = 8 dB TYP. @f = 1.0 GHz, V<sub>CE</sub> = 10 V, I<sub>c</sub> = 5.0 mA
- Wide dynamic range : NF = 1.9 dB, Ga = 9 dB @f = 1 GHz, V<sub>CE</sub> = 10 V, I<sub>c</sub> = 15 mA

#### ORDERING INFORMATION

| Part Number | Quantity                               |
|-------------|--|
| 2SC2570A    | Loose products (500 pcs)               |
| 2SC2570A-T  | Taping products (Box type) (2 500 pcs) |

**Remark** To order evaluation samples, please contact your NEC sales office (available in 500-pcs units).

#### ABSOLUTE MAXIMUM RATINGS (T<sub>A</sub> = +25 °C)

| Parameter                    | Symbol           | Ratings     | Unit |
|------------------------------|------------------|-------------|------|
| Collector to Base Voltage    | V <sub>CB0</sub> | 25          | V    |
| Collector to Emitter Voltage | V <sub>CE0</sub> | 12          | V    |
| Emitter to Base Voltage      | V <sub>EB0</sub> | 3.0         | V    |
| Collector Current            | I <sub>c</sub>   | 70          | mA   |
| Total Power Dissipation      | P <sub>tot</sub> | 600         | mW   |
| Junction Temperature         | T <sub>j</sub>   | 150         | °C   |
| Storage Temperature          | T <sub>stg</sub> | -65 to +150 | °C   |

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Not all devices/types available in every country. Please check with local NEC representative for availability and additional information.

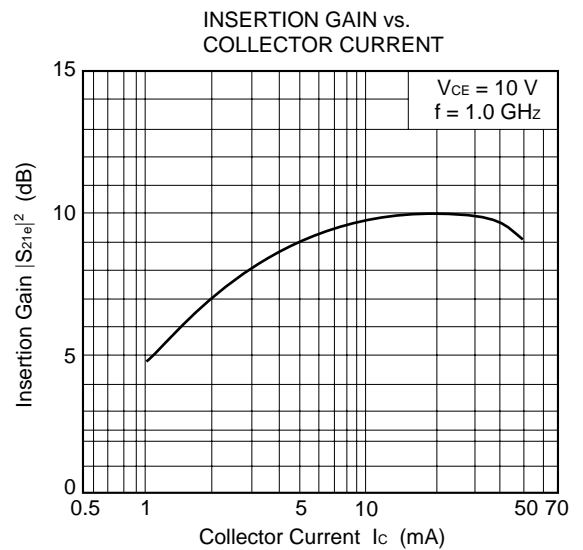
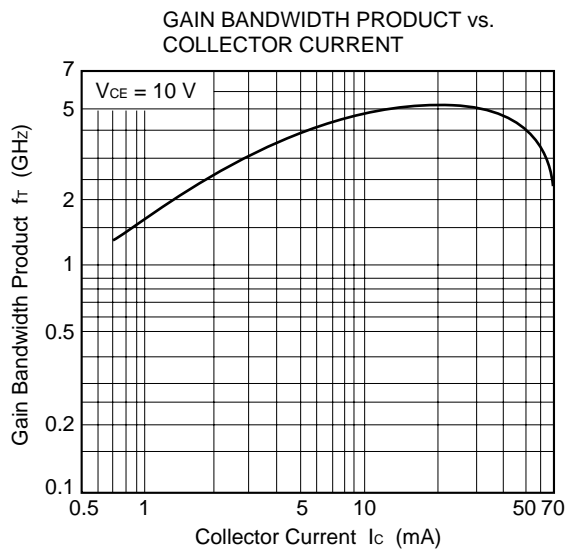
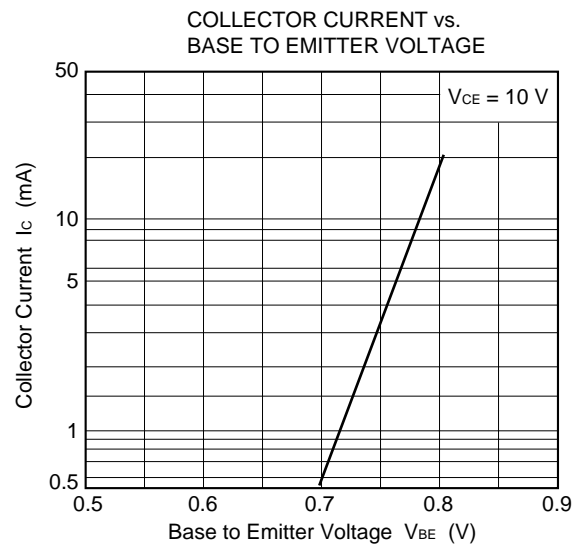
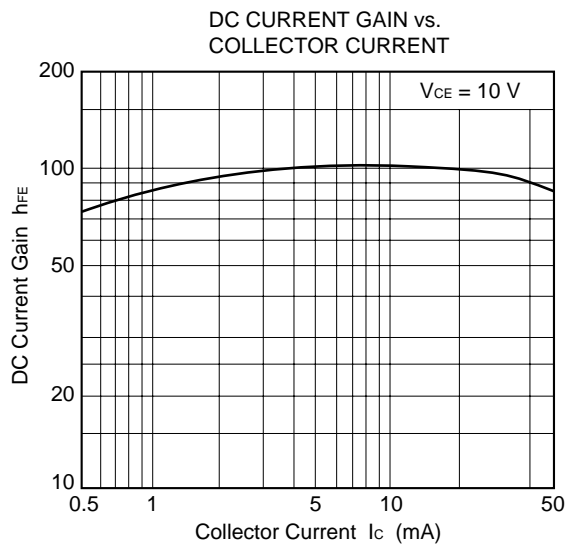
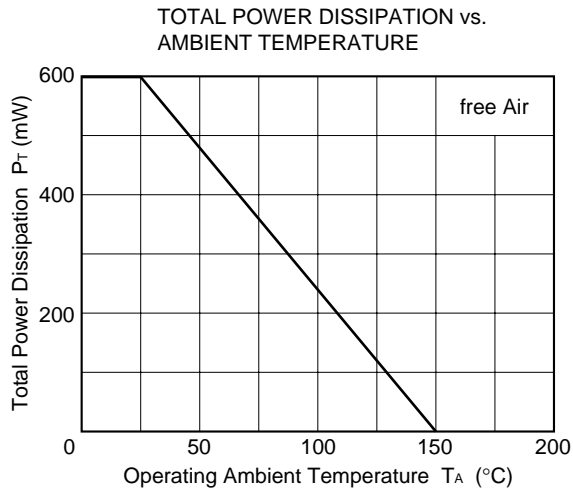
**ELECTRICAL CHARACTERISTICS (T<sub>A</sub> = +25 °C)**

| Parameter                | Symbol                     | Test Conditions  | MIN. | TYP. | MAX. | Unit          |
|--------------------------|----------------------------|--|------|------|------|---------------|
| DC Current Gain          | $h_{FE}$ <sup>Note 1</sup> | $V_{CE} = 10\text{ V}, I_C = 20\text{ mA}$                     | 40   | –    | 200  | –             |
| Gain Bandwidth Product   | $f_T$                      | $V_{CE} = 10\text{ V}, I_C = 20\text{ mA}$                     | –    | 5.0  | –    | GHz           |
| Output Capacitance       | $C_{Ob}$ <sup>Note 2</sup> | $V_{CB} = 10\text{ V}, I_E = 0, f = 1.0\text{ MHz}$            | –    | 0.7  | 0.9  | pF            |
| Insertion Power Gain     | $ S_{21e} ^2$              | $V_{CE} = 10\text{ V}, I_C = 20\text{ mA}, f = 1.0\text{ GHz}$ | 8    | 10   | –    | dB            |
| Noise Figure             | NF                         | $V_{CE} = 10\text{ V}, I_C = 5\text{ mA}, f = 1.0\text{ GHz}$  | –    | 1.5  | 3.0  | dB            |
| Maximum Available Gain   | MAG                        | $V_{CE} = 10\text{ V}, I_C = 20\text{ mA}, f = 1.0\text{ GHz}$ | –    | 11.5 | –    | dB            |
| Collector Cutoff Current | $I_{CBO}$                  | $V_{CB} = 15\text{ V}, I_E = 0$                                | –    | –    | 0.1  | $\mu\text{A}$ |
| Emitter Cutoff Current   | $I_{EBO}$                  | $V_{EB} = 2.0\text{ V}, I_C = 0$                               | –    | –    | 0.1  | $\mu\text{A}$ |

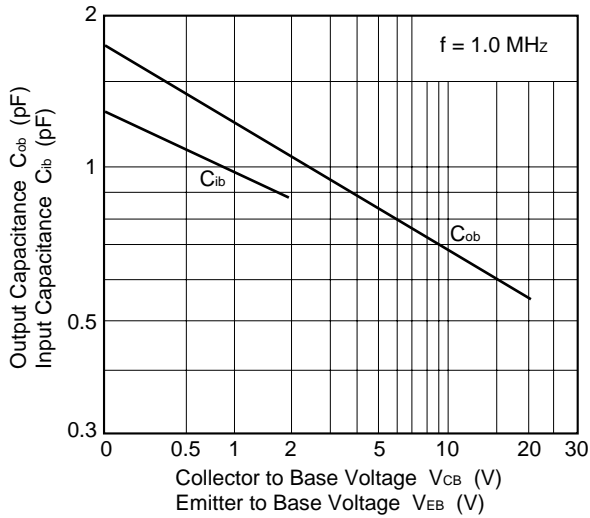
**Notes** 1. Pulse Measurement:  $PW \leq 350\ \mu\text{s}$ , Duty Cycle  $\leq 2\%$

2. The emitter and case terminal should be connected to the guard terminal of the capacitance bridge.

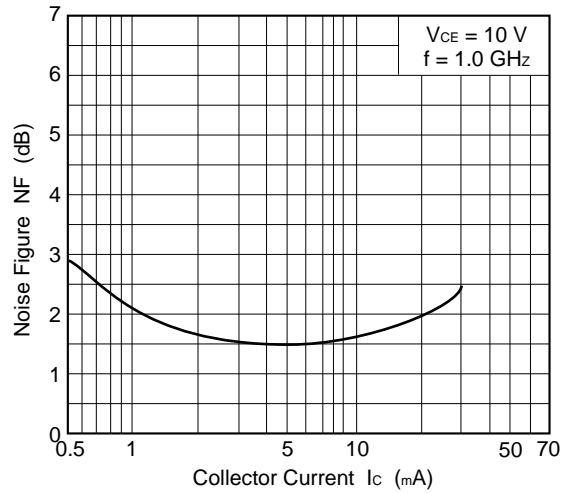
TYPICAL CHARACTERISTICS (T<sub>A</sub> = +25 °C)



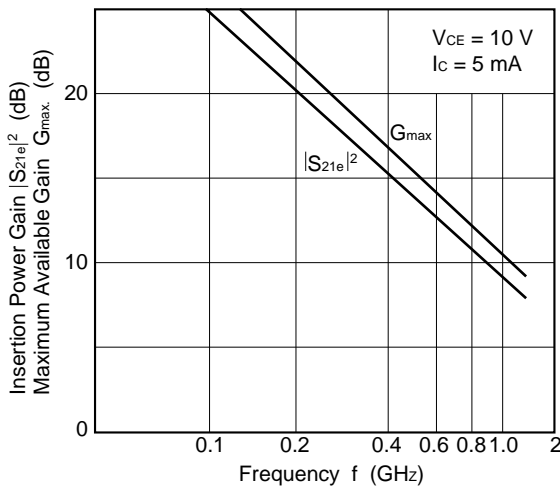
OUTPUT AND INPUT CAPACITANCE vs. REVERSE VOLTAGE



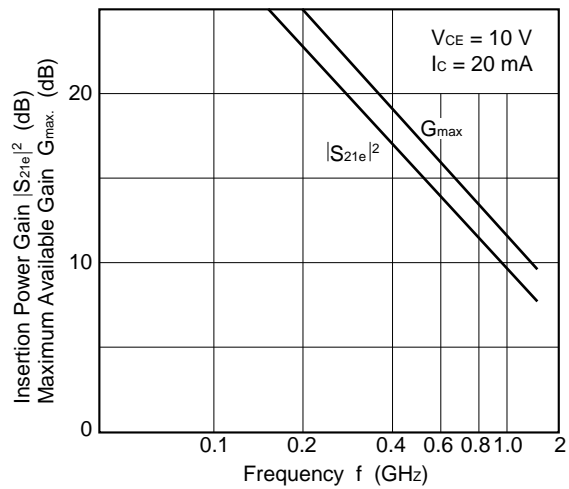
NOISE FIGURE vs. COLLECTOR CURRENT



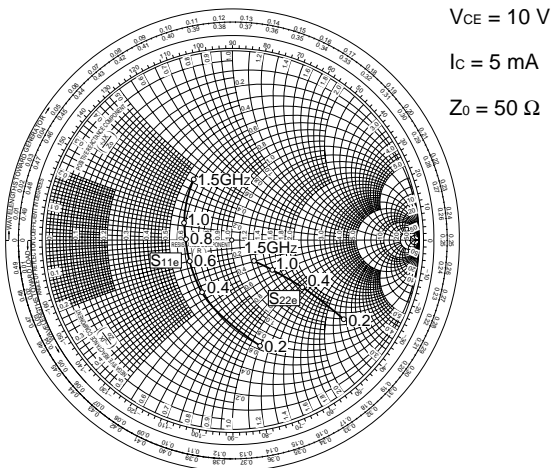
INSERTION POWER GAIN, MAXIMUM AVAILABLE GAIN vs. FREQUENCY



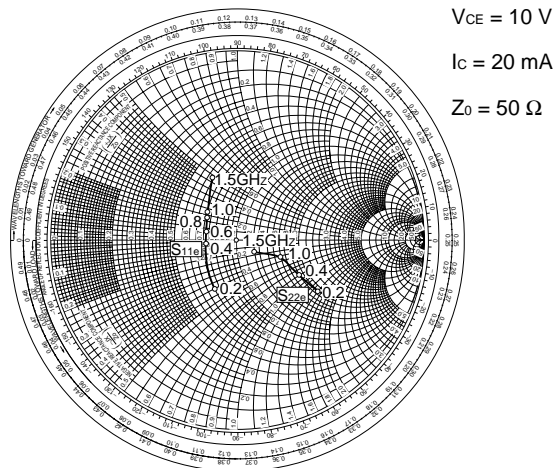
INSERTION POWER GAIN, MAXIMUM AVAILABLE GAIN vs. FREQUENCY



S-PARAMETER

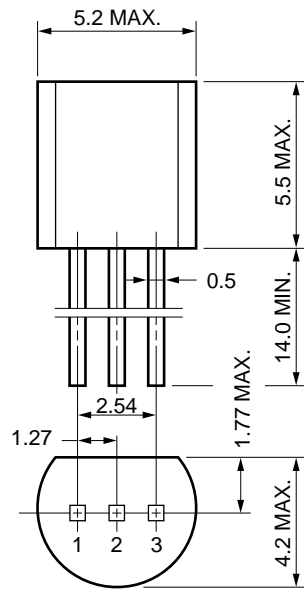


S-PARAMETER



PACKAGE DIMENSION

TO-92 (UNIT:mm)



- |              |       |          |
|--------------|-------|----------|
| 1. BASE      | EIAJ  | : SC-43B |
| 2. EMITTER   | JEDEC | : TO-92  |
| 3. COLLECTOR | IEC   | : PA33   |

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